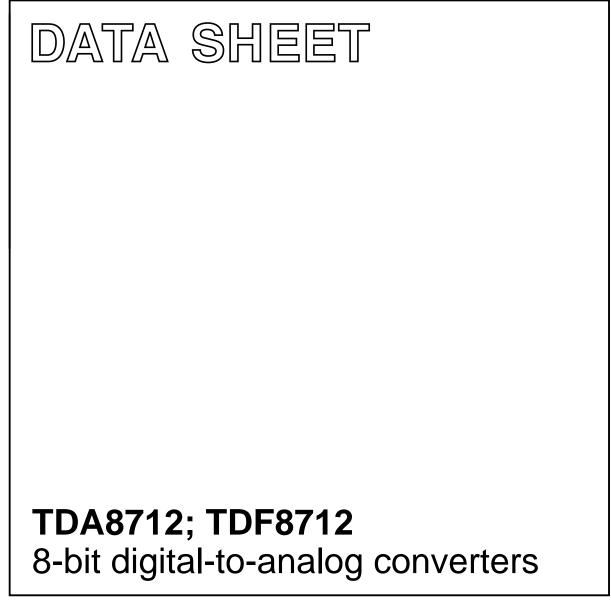
### INTEGRATED CIRCUITS



Product specification Supersedes data of April 1993 File under Integrated Circuits, IC02 June 1994

## **Philips Semiconductors**





**TDA8712; TDF8712** 

#### 8-bit digital-to-analog converters

#### FEATURES

- 8-bit resolution
- · Conversion rate up to 50 MHz
- TTL input levels
- Internal reference voltage generator
- Two complementary analog voltage outputs
- No deglitching circuit required
- Internal input register
- Low power dissipation
- Internal 75  $\Omega$  output load (connected to the analog supply)
- · Very few external components required
- Temperature range
  - TDA8712: 0 to 70 °C
  - TDF8712: -40 to +85 °C.

### APPLICATIONS

- High-speed digital-to-analog conversion
- Digital TV including:
  - field progressive scan
  - line progressive scan
- Subscriber TV decoders
- Satellite TV decoders
- Digital VCRs
- Industrial and automotive.

#### **GENERAL DESCRIPTION**

The TDA8712 and TDF8712 are 8-bit digital-to-analog converters (DACs) for video and other applications. They convert the digital input signal into an analog voltage output at a maximum conversion rate of 50 MHz. No external reference voltage is required and all digital inputs are TTL compatible.

TYPE NUMBER		PA	CKAGE	
	PINS	PIN POSITION	MATERIAL	CODE
TDA8712	16	DIP	plastic	SOT38-1
TDF8712	16	DIP	plastic	SOT38-1
TDA8712T	16	SO16L	plastic	SOT162-1
TDF8712T	16	SO16L	plastic	SOT162-1

#### ORDERING INFORMATION

### TDA8712; TDF8712

#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>CCA</sub>	analog supply voltage					
	TDA8712		4.5	5.0	5.5	V
	TDF8712		4.75	5.0	5.25	V
V <sub>CCD</sub>	digital supply voltage					
	TDA8712		4.5	5.0	5.5	V
	TDF8712		4.75	5.0	5.25	V
I <sub>CCA</sub>	analog supply current	note 1	20	26	32	mA
I <sub>CCD</sub>	digital supply current	note 1	16	23	30	mA
$\Delta V_{OUT(p-p)}$	full-scale analog output voltage	$Z_L = 10 \text{ k}\Omega$ ; note 2	-1.45	-1.60	-1.75	V
	differences between V <sub>OUT</sub> and $\overline{V}_{OUT}$ (peak-to-peak value)	$Z_L = 75 \Omega$ ; note 2	-0.72	0.80	-0.88	V
ILE	DC integral linear error		-	±0.3	±0.5	LSB
DLE	DC differential linearity error		-	±0.3	±0.5	LSB
f <sub>clk(max)</sub>	maximum conversion rate		50	-	-	MHz
В	-3 dB analog bandwidth	f <sub>clk</sub> = 50 MHz; note 3	-	150	-	MHz
P <sub>tot</sub>	total power dissipation					
	TDA8712		160	250	340	mW
	TDF8712		170	250	325	mW

#### Notes

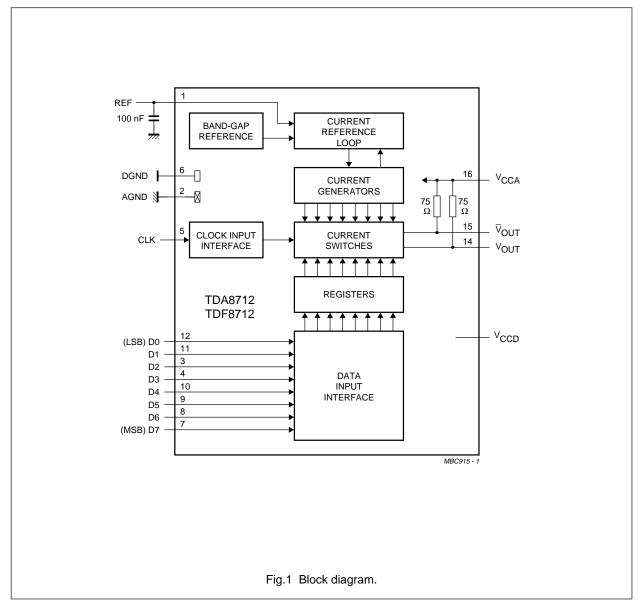
1. D0 to D7 are connected to  $V_{CCD}$  and CLK is connected to DGND.

2. The analog output voltages (V<sub>OUT</sub> and  $\overline{V}_{OUT}$ ) are negative with respect to V<sub>CCA</sub> (see Table 1). The output resistance between V<sub>CCA</sub> and each of these outputs is typically 75  $\Omega$ .

3. The –3 dB analog output bandwidth is determined by real time analysis of the output transient at a maximum input code transition (code 0 to 255).

### TDA8712; TDF8712

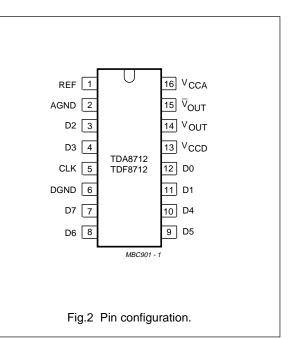
#### **BLOCK DIAGRAM**



### TDA8712; TDF8712

#### PINNING

SYMBOL	PIN	DESCRIPTION
REF	1	voltage reference (decoupling)
AGND	2	analog ground
D2	3	data input; bit 2
D3	4	data input; bit 3
CLK	5	clock input
DGND	6	digital ground
D7	7	data input; bit 7 (MSB)
D6	8	data input; bit 6
D5	9	data input; bit 5
D4	10	data input; bit 4
D1	11	data input; bit 1
D0	12	data input; bit 0 (LSB)
V <sub>CCD</sub>	13	digital supply voltage (+5 V)
V <sub>OUT</sub>	14	analog output voltage
Vout	15	complimentary analog output voltage
V <sub>CCA</sub>	16	analog supply voltage (+5 V)



### TDA8712; TDF8712

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>CCA</sub>	analog supply voltage	-0.3	+7.0	V
V <sub>CCD</sub>	digital supply voltage	-0.3	+7.0	V
$\Delta V_{CC}$	supply voltage differences between $V_{\text{CCA}}$ and $V_{\text{CCD}}$	-0.5	+0.5	V
$\Delta V_{GND}$	ground voltage differences between $V_{\mbox{\scriptsize AGND}}$ and $V_{\mbox{\scriptsize DGND}}$	-0.1	+0.1	V
VI	input voltage (pins 3 to 5 and 7 to 12)	-0.3	V <sub>CCD</sub>	V
I <sub>tot</sub>	total output current ( $I_{OUT}$ + $\overline{I}_{OUT}$ ; pins 14 and 15)	-5	+26	mA
T <sub>stg</sub>	storage temperature	-55	+150	°C
T <sub>amb</sub>	operating ambient temperature			
	TDA8712	0	+70	°C
	TDF8712	-40	+85	°C
Tj	junction temperature	-	+150	°C

#### HANDLING

Inputs and outputs are protected against electrostatic discharges in normal handling. However, to be totally safe, it is desirable to take normal precautions appropriate to handling integrated circuits.

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient in free air		
	SOT38-1	70	K/W
	SOT162-1	90	K/W

#### TDA8712; TDF8712

#### CHARACTERISTICS

 $V_{CCA} = V_{16} \text{ to } V_2 = 4.5 \text{ to } 5.5 \text{ V (TDA8712)} = 4.75 \text{ to } 5.25 \text{ V (TDF8712)}; V_{CCD} = V_{13} \text{ to } V_6 = 4.5 \text{ to } 5.5 \text{ V (TDA8712)} = 4.75 \text{ to } 5.25 \text{ V (TDF8712)}; V_{CCA} \text{ to } V_{CCD} = -0.5 \text{ to } +0.5 \text{ V (TDA8712)} = -0.25 \text{ to } +0.25 \text{ V (TDF8712)}; \text{REF decoupled to AGND via a 100 nF capacitor; } T_{amb} = -40 \text{ to } +85 \text{ °C}; \text{ AGND and DGND shorted together; typical readings taken at } V_{CCA} = V_{CCD} = 5 \text{ V and } T_{amb} = 25 \text{ °C}; \text{ unless otherwise specified.}$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Supply			-			-
V <sub>CCA</sub>	analog supply voltage					
	TDA8712		4.5	5.0	5.5	V
	TDF8712		4.75	5.0	5.25	V
V <sub>CCD</sub>	digital supply voltage					
	TDA8712		4.5	5.0	5.5	V
	TDF8712		4.75	5.0	5.25	V
ССА	analog supply current	note 1	20	26	32	mA
ССD	digital supply current	note 1	16	23	30	mA
ΔV <sub>GND</sub>	ground voltage differences between V <sub>AGND</sub> and V <sub>DGND</sub>		-0.1	-	+0.1	V
Inputs		•	•	ł		
DIGITAL INPUT	S (D7 TO D0) AND CLOCK INPUT CLK					
V <sub>IL</sub>	LOW level input voltage		0	-	0.8	V
V <sub>IH</sub>	HIGH level input voltage		2.0	-	V <sub>CCD</sub>	V
IL	LOW level input current	V <sub>I</sub> = 0.4 V	-	-0.3	-0.4	mA
I <sub>IH</sub>	HIGH level input current	V <sub>I</sub> = 2.7 V	-	0.01	20	μA
f <sub>clk(max)</sub>	maximum clock frequency		50	-	-	MHz
	erenced to V <sub>CCA</sub> )	•		ł	I.	
ΔV <sub>OUT(p-p)</sub>	full-scale analog output voltage	$Z_L = 10 \text{ k}\Omega$ ; note 2	-1.45	-1.60	-1.75	V
	differences between $V_{\text{OUT}}$ and $\overline{V}_{\text{OUT}}$ (peak-to-peak value)	$Z_L = 75 \Omega$ ; note 2	-0.72	0.80	-0.88	V
V <sub>os</sub>	analog offset output voltage	code = 0	-	-3	-25	mV
TC <sub>VOUT</sub>	full-scale analog output voltage temperature coefficient		-	-	200	μV/K
TC <sub>Vos</sub>	analog offset output voltage temperature coefficient		-	-	20	μV/K
В	-3 dB analog bandwidth	f <sub>clk</sub> = 50 MHz; note 3	-	150	-	MHz
G <sub>diff</sub>	differential gain		-	0.6	-	%
φdiff	differential phase		-	1	-	deg
Zo	output impedance		-	75	-	Ω
Transfer fund	ction (f <sub>clk</sub> = 50 MHz)		1			
ILE	DC integral linear error		-	±0.3	±0.5	LSB
DLE	DC differential linearity error		_	±0.3	±0.5	LSB

### TDA8712; TDF8712

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Switching ch	aracteristics (f <sub>clk</sub> = 50 MHz; notes	s 4 and 5; see Figs 3, 4	and 5)	-	-	
t <sub>SU;DAT</sub>	data set-up time		-0.3	-	-	ns
t <sub>HD;DAT</sub>	data hold time		2.0	-	-	ns
t <sub>PD</sub>	propagation delay time		-	-	1.0	ns
t <sub>S1</sub>	settling time 1	10% to 90% full-scale change to ±1 LSB	-	1.1	1.5	ns
t <sub>S2</sub>	settling time 2	10% to 90% full-scale change to ±1 LSB	-	6.5	8.0	ns
t <sub>d</sub>	input to 50% output delay time		-	3.0	5.0	ns
Output transi	ients (glitches; f <sub>clk</sub> = 50 MHz; not	e 6; see Fig.6)	1			
Eg	glitch energy from code	transition 127 to 128	_	-	30	LSB.ns

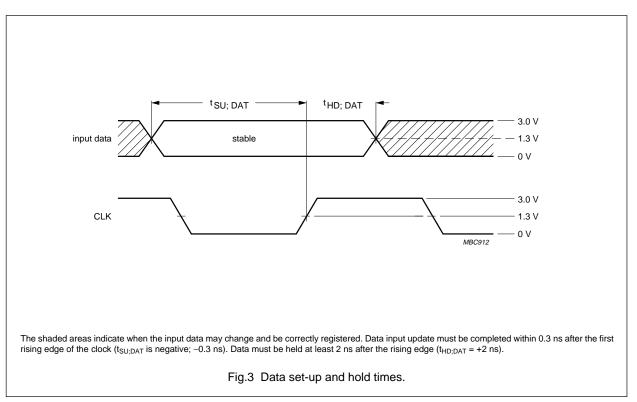
#### Notes

- 1. D0 to D7 are connected to V<sub>CCD</sub> and CLK is connected to DGND.
- 2. The analog output voltages (V<sub>OUT</sub> and  $\overline{V}_{OUT}$ ) are negative with respect to V<sub>CCA</sub> (see Table 1). The output resistance between V<sub>CCA</sub> and each of these outputs is typically 75  $\Omega$ .
- 3. The –3 dB analog output bandwidth is determined by real time analysis of the output transient at a maximum input code transition (code 0 to 255).
- 4. The worst case characteristics are obtained at the transition from input code 0 to 255 and if an external load impedance greater than 75 Ω is connected between V<sub>OUT</sub> or V<sub>OUT</sub> and V<sub>CCA</sub>. The specified values have been measured with an active probe between V<sub>OUT</sub> and AGND. No further load impedance between V<sub>OUT</sub> and AGND has been applied. All input data is latched at the rising edge of the clock. The output voltage remains stable (independent of input data variations) during the HIGH level of the clock (CLK = HIGH). During a LOW-to-HIGH transition of the clock (CLK = LOW), the DAC operates in the transparent mode (input data will be directly transferred to their corresponding analog output voltages; see Fig.5.
- 5. The data set-up time (t<sub>SU;DAT</sub>) is the minimum period preceding the rising edge of the clock that the input data must be stable in order to be correctly registered. A negative set-up time indicates that the data may be initiated after the rising edge of the clock and still be recognized. The data hold time (t<sub>HD;DAT</sub>) is the minimum period following the rising edge of the clock that the input data must be stable in order to be correctly registered. A negative stable in order to be correctly registered. A negative hold time indicates that the data may be released prior to the rising edge of the clock and still be recognized.
- 6. The definition of glitch energy and the measurement set-up are shown in Fig.6. The glitch energy is measured at the input transition between code 127 and 128 and on the falling edge of the clock.

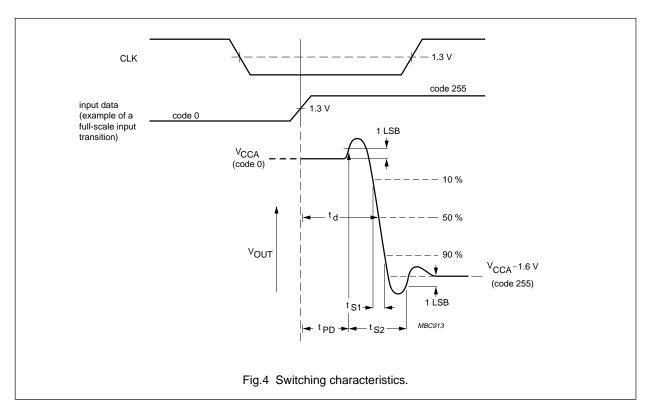
### TDA8712; TDF8712

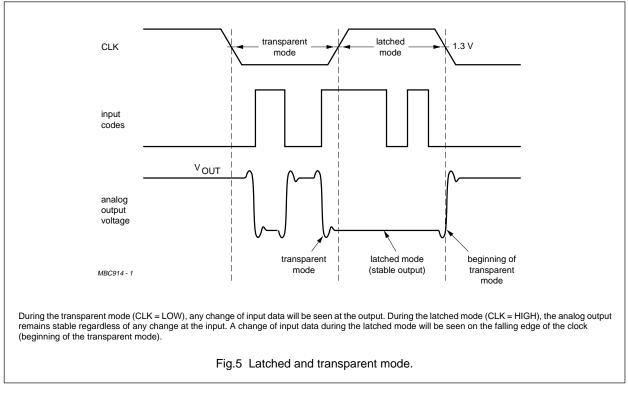
		DAC OUTPUT VOLTAGES (V)			/)	
CODE	INPUT DATA (D7 to D0)	<b>Ζ</b> <sub>L</sub> = 10 kΩ		INPUT DATA (D7 to D0) $Z_L = 10 \text{ k}\Omega$ $Z_L =$		<b>75</b> Ω
		V <sub>OUT</sub>	<b>V</b> <sub>OUT</sub>	V <sub>OUT</sub>	V <sub>OUT</sub>	
0	000 00 00	0	-1.6	0	-0.8	
1	000 000 01	-0.006	-1.594	-0.003	-0.797	
128	100 000 00	-0.8	-0.8	-0.4	-0.4	
254	111 111 10	-1.594	-0.006	-0.797	-0.003	
255	111 111 11	-1.6	0	-0.8	0	

Table 1 Input coding and output voltages (typical values; referenced to V<sub>CCA</sub>, regardless of the offset voltage).

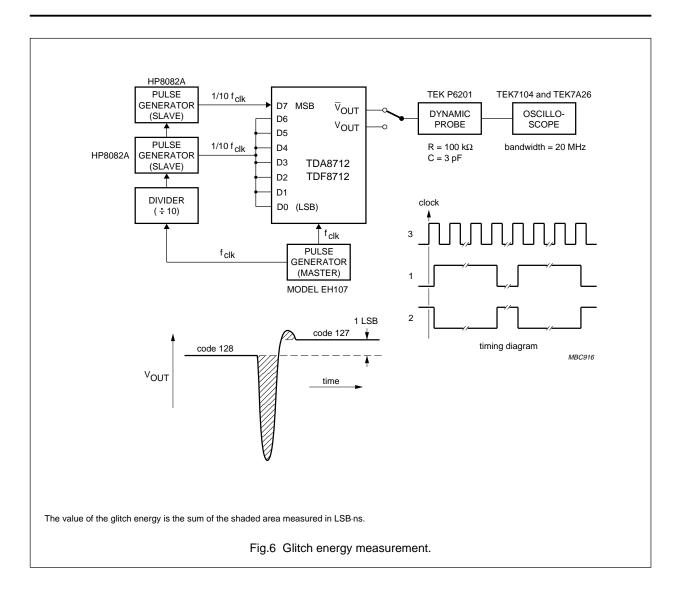


#### TDA8712; TDF8712



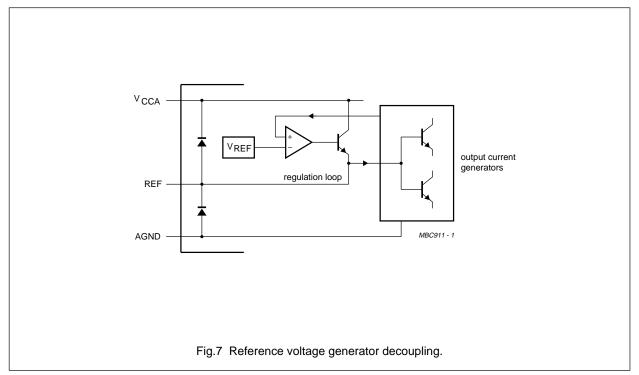


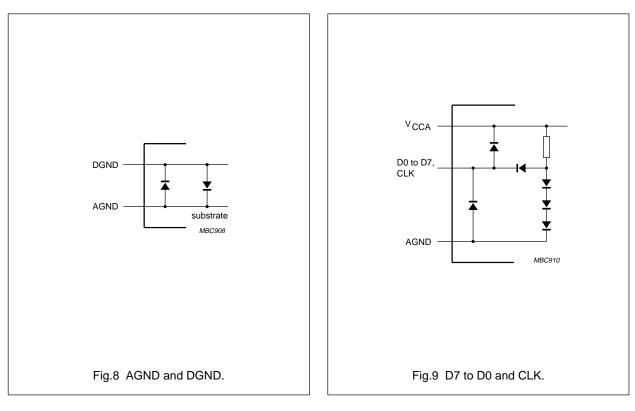
#### TDA8712; TDF8712



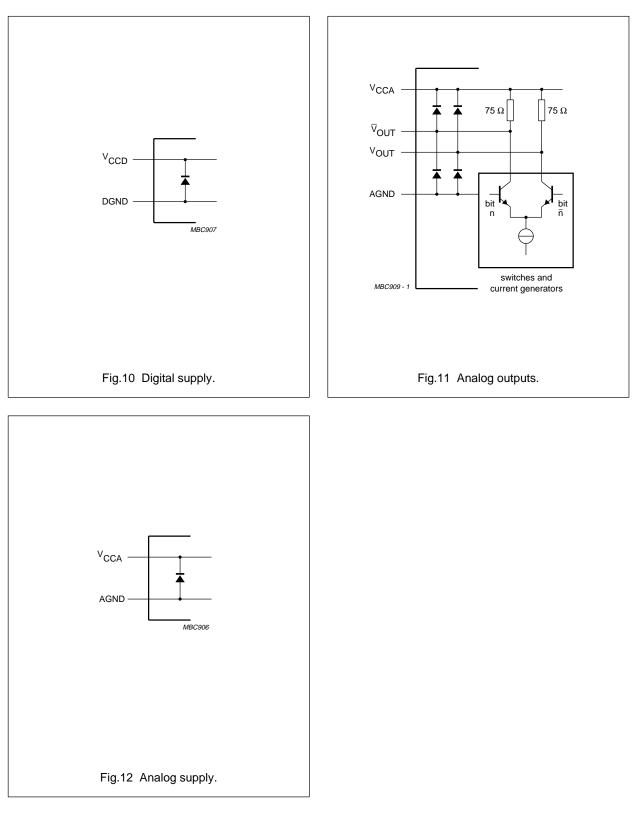
### TDA8712; TDF8712

#### **INTERNAL PIN CONFIGURATIONS**





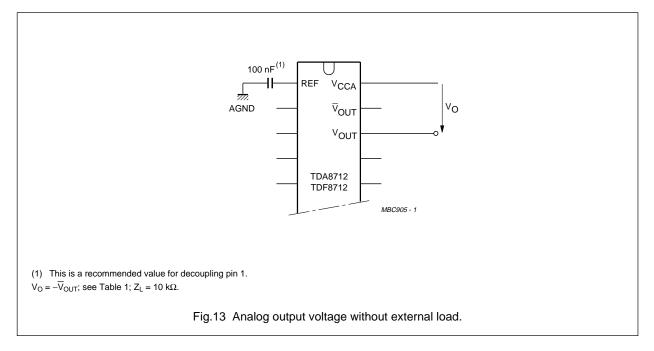
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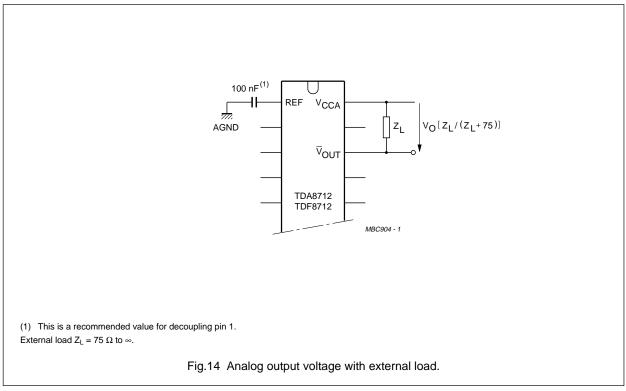


#### TDA8712; TDF8712

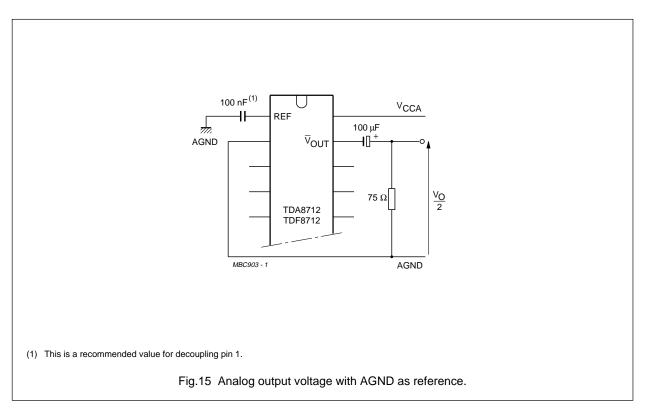
#### **APPLICATION INFORMATION**

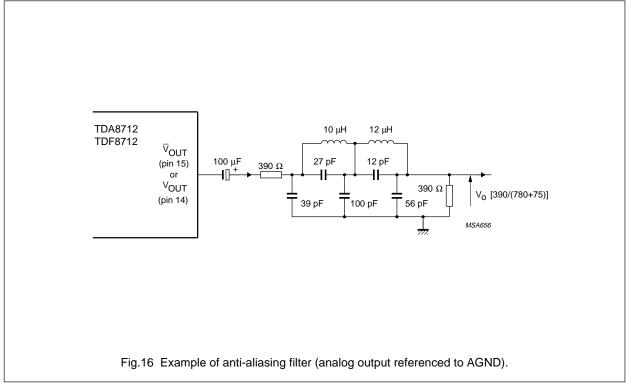
Additional application information can be supplied on request (please quote "FTV/8901").



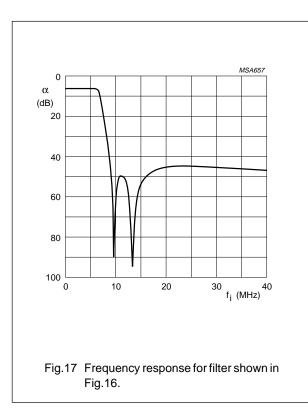


### TDA8712; TDF8712



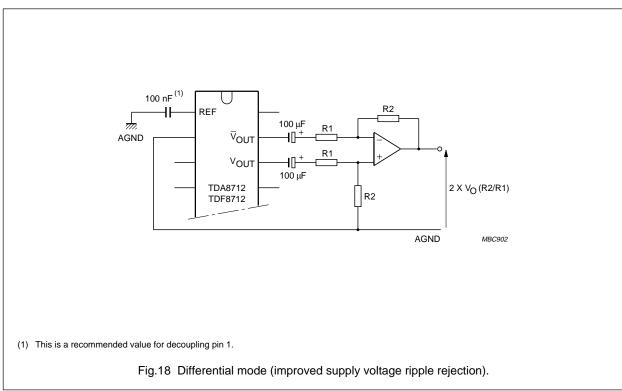


### TDA8712; TDF8712



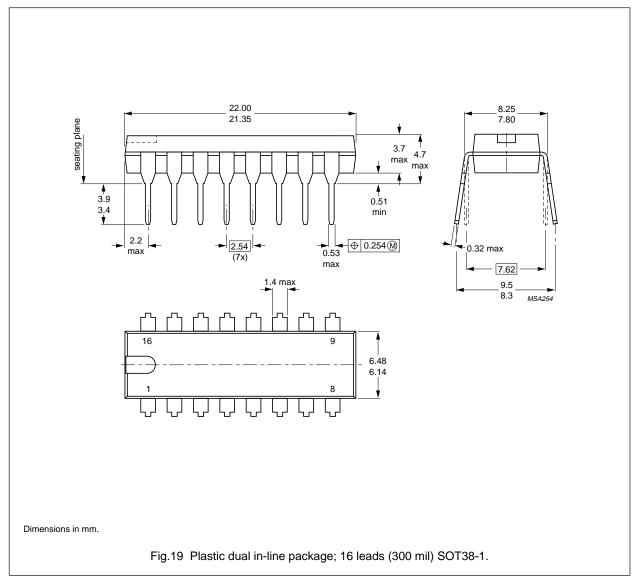
#### Characteristics of Fig. 17

- Order 5; adapted CHEBYSHEV
- Ripple  $\rho \leq 0.1 \mbox{ dB}$
- f = 6.7 MHz at -3 dB
- $f_{notch} = 9.7$  MHz and 13.3 MHz.

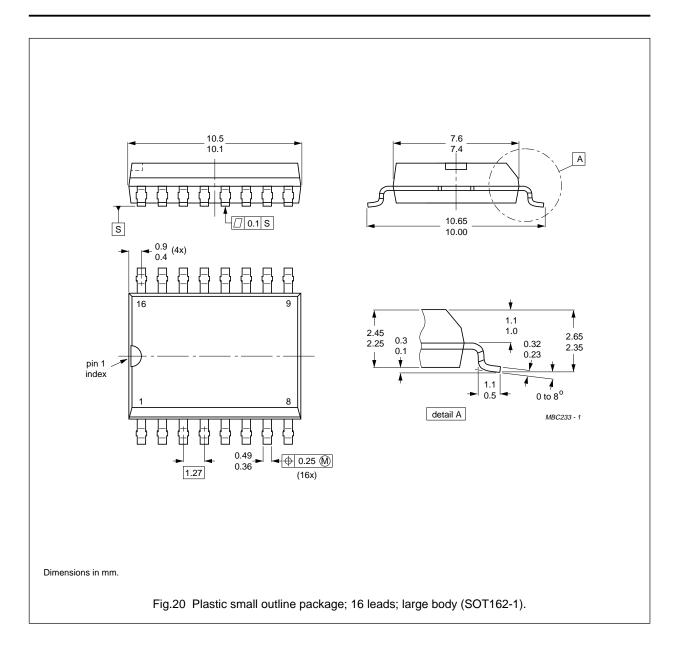


### TDA8712; TDF8712

#### PACKAGE OUTLINES



### TDA8712; TDF8712



#### SOLDERING

#### Plastic dual in-line packages

#### BY DIP OR WAVE

The maximum permissible temperature of the solder is 260 °C; this temperature must not be in contact with the joint for more than 5 s. The total contact time of successive solder waves must not exceed 5 s.

The device may be mounted up to the seating plane, but the temperature of the plastic body must not exceed the specified storage maximum. If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature within the permissible limit.

#### REPAIRING SOLDERED JOINTS

Apply a low voltage soldering iron below the seating plane (or not more than 2 mm above it). If its temperature is below 300 °C, it must not be in contact for more than 10 s; if between 300 and 400 °C, for not more than 5 s.

#### Plastic small-outline packages

#### BY WAVE

During placement and before soldering, the component must be fixed with a droplet of adhesive. After curing the adhesive, the component can be soldered. The adhesive can be applied by screen printing, pin transfer or syringe dispensing.

Maximum permissible solder temperature is 260 °C, and maximum duration of package immersion in solder bath is 10 s, if allowed to cool to less than 150 °C within 6 s. Typical dwell time is 4 s at 250 °C.

## TDA8712; TDF8712

A modified wave soldering technique is recommended using two solder waves (dual-wave), in which a turbulent wave with high upward pressure is followed by a smooth laminar wave. Using a mildly-activated flux eliminates the need for removal of corrosive residues in most applications.

#### BY SOLDER PASTE REFLOW

Reflow soldering requires the solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the substrate by screen printing, stencilling or pressure-syringe dispensing before device placement.

Several techniques exist for reflowing; for example, thermal conduction by heated belt, infrared, and vapour-phase reflow. Dwell times vary between 50 and 300 s according to method. Typical reflow temperatures range from 215 to 250 °C.

Preheating is necessary to dry the paste and evaporate the binding agent. Preheating duration: 45 min at 45  $^\circ$ C.

REPAIRING SOLDERED JOINTS (BY HAND-HELD SOLDERING IRON OR PULSE-HEATED SOLDER TOOL)

Fix the component by first soldering two, diagonally opposite, end pins. Apply the heating tool to the flat part of the pin only. Contact time must be limited to 10 s at up to 300 °C. When using proper tools, all other pins can be soldered in one operation within 2 to 5 s at between 270 and 320 °C. (Pulse-heated soldering is not recommended for SO packages.)

For pulse-heated solder tool (resistance) soldering of VSO packages, solder is applied to the substrate by dipping or by an extra thick tin/lead plating before package placement.

### TDA8712; TDF8712

#### DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
more of the limiting values of the device at these or at	accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or may cause permanent damage to the device. These are stress ratings only and operation any other conditions above those given in the Characteristics sections of the specification limiting values for extended periods may affect device reliability.
Application information	

Where application information is given, it is advisory and does not form part of the specification.

#### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

### TDA8712; TDF8712

NOTES

### TDA8712; TDF8712

NOTES

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NOTES

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